



DMT8030LFDF

### **Product Summary**

BV <sub>DSS</sub>	Rds(on) max	I <sub>D MAX</sub> Та = +25°С
2014	$25m\Omega @ V_{GS} = 10V$	7.5A
80V	38mΩ @ Vgs = 4.5V	6.1A

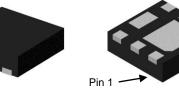
### Description

This new generation MOSFET is designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

### Applications

- **Power Management Functions**
- Battery Operated Systems and Solid-State Relays
- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories, Transistors, etc.

U-DFN2020-6 (Type F)



Top View

Bottom View

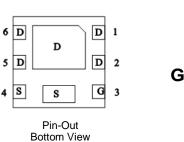
### 80V N-CHANNEL ENHANCEMENT MODE MOSFET

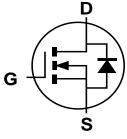
### Features and Benefits

- 0.6mm Profile Ideal for Low Profile Applications
- PCB Footprint of 4mm<sup>2</sup>
- Low On-Resistance
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

### **Mechanical Data**

- Case: U-DFN2020-6
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @
- Weight: 0.0065 grams (Approximate)





Equivalent Circuit

### Ordering Information (Note 4)

Part Number	Case	Quantity per Reel
DMT8030LFDF-7	U-DFN2020-6 (Type F)	3,000
DMT8030LFDF-13	U-DFN2020-6 (Type F)	10,000

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + CI) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

### **Marking Information**

U-DFN2020-6 (Type	e F)
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83 = Product Type Marking Code

YWX = Date Code Marking

Y = Year (ex: 0 = 2020)

W = Week (ex: a = week 27; z represents week 52 and 53)

X = Internal Code (ex: U = Monday)

Date	Code	Kev

Notes:

ale Code Key												
Year	2019	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	9	0	1	2	3	4	5	6	7	8	9	0
Week 1-26			27-52			53						
Code		A	-Z			a	-Z				Z	
Internal Code	Sur	۱ I	Mon		Tue Wed Thu			Thu		Fri		Sat
Code	Т		U		V	V	V	Х		Y		Ζ



# Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	VDSS	80	V	
Gate-Source Voltage	V <sub>GSS</sub>	±20	V	
	T <sub>A</sub> = +25°C	1-	7.5	A
Continuous Drain Current, VGS = 10V (Note 6)	T <sub>A</sub> = +70°C	ID	6.1	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		ldм	40	A
Maximum Body Diode Continuous Current		ls	7.5	A
Pulsed Body Diode Current (10µs Pulse, T <sub>C</sub> = +25°C, Packa	age Limited)	Ism	40	A
Avalanche Current, L = 0.3mH	las	12.5	A	
Avalanche Energy, L = 0.3mH	Eas	23.4	mJ	

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Dower Dissipation (Note 5)	T <sub>A</sub> = +25°C	D-	1.2	W
Total Power Dissipation (Note 5)	T <sub>A</sub> = +70°C	PD	0.7	vv
Thermal Resistance, Junction to Ambient (Note 5)	RθJA	103	°C/W	
Total Dawar Dissinction (Note 6)	T <sub>A</sub> = +25°C	P	2.2	W
Total Power Dissipation (Note 6)	T <sub>A</sub> = +70°C	PD	1.4	vv
Thermal Resistance, Junction to Ambient (Note 6)	RθJA	58	°C/W	
Thermal Resistance, Junction to Case (Note 6)	Rejc	6.7	0/11	
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

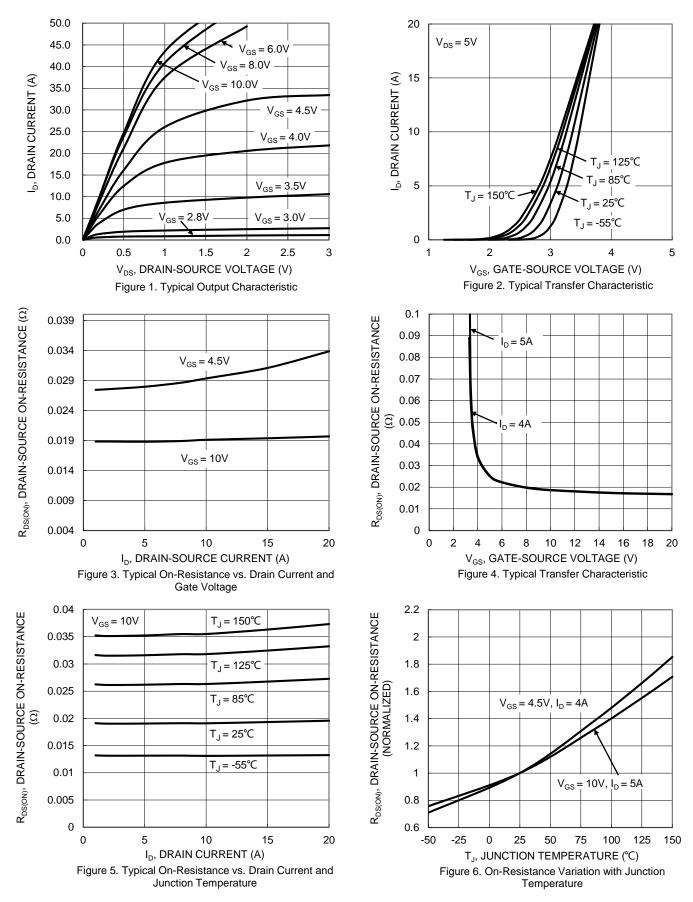
### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)	Cymber		• 76	max	Unit		
Drain-Source Breakdown Voltage	BVDSS	80	_	_	V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	IDSS		—	1	μA	$V_{DS} = 64V, V_{GS} = 0V$	
Gate-Source Leakage	Igss	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	Vgs(th)	1.2	—	2.5	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	Descent		23.8	25	mΩ	$V_{GS} = 10V, I_{D} = 5A$	
	Rds(on)		33.6	38	11152	$V_{GS} = 4.5V, I_D = 4A$	
Diode Forward Voltage	Vsd		0.7	1.2	V	$V_{GS} = 0V$ , $I_{S} = 10A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	_	641	—			
Output Capacitance	Coss	—	272	—	pF	$V_{DS} = 25V, V_{GS} = 0V,$ f = 1.0MHz	
Reverse Transfer Capacitance	Crss	_	32	—			
Gate Resistance	Rg	_	1.4	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg		5.4	—			
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg		10.4	_	nC		
Gate-Source Charge	Qgs	_	1.8	—	nc	$V_{DS} = 40V, I_{D} = 7.5A$	
Gate-Drain Charge	Q <sub>gd</sub>		2.4	—			
Turn-On Delay Time	t <sub>D(ON)</sub>		11.3	—		N/ 101/	
Turn-On Rise Time	t <sub>R</sub>		14.3	—		$V_{DD} = 40V,$	
Turn-Off Delay Time	tD(OFF)	—	10.8	—	ns	$V_{GS} = 4.5V, R_g = 2.7\Omega,$ ID = 10A	
Turn-Off Fall Time	tF		8.3				
Body Diode Reverse Recovery Time	t <sub>RR</sub>		25.5	_	ns	I <sub>F</sub> = 7.5A, di/dt = 100A/µs	
Body Diode Reverse Recovery Charge	Qrr	_	20.6	—	nC	IF = 7.5A, di/dt = 100A/µs	

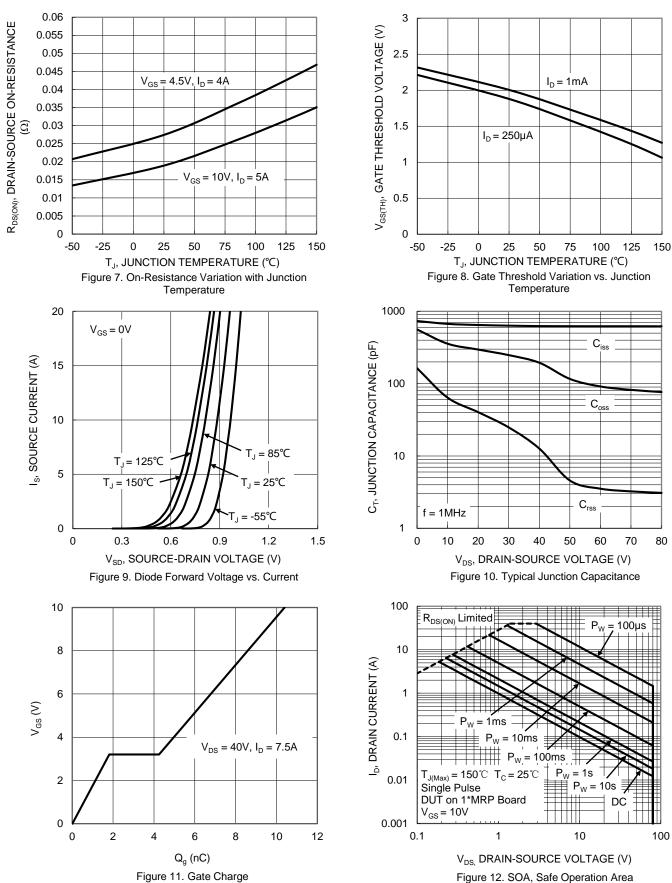
 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
7. Short duration pulse test used to minimize self-heating effect.
8. Guaranteed by design. Not subject to product testing. Notes:



### DMT8030LFDF

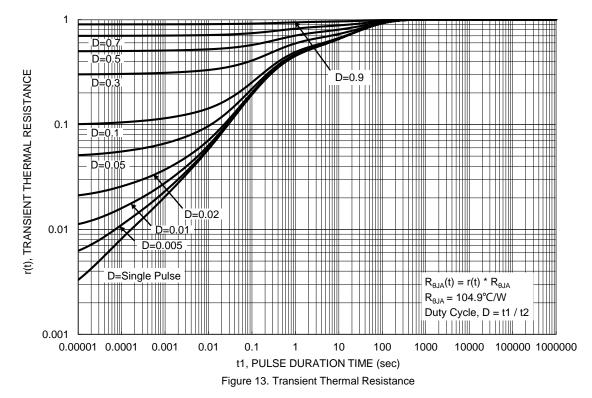






DMT8030LFDF Datasheet number: DS41903 Rev. 3 - 2

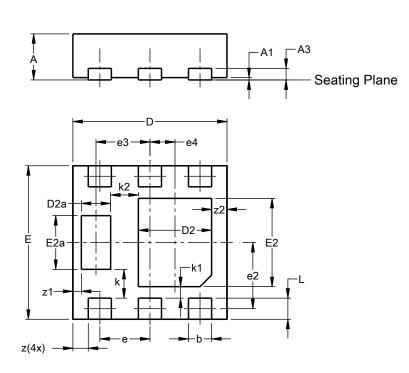






### **Package Outline Dimension**

Please see http://www.diodes.com/package-outlines.html for the latest version.



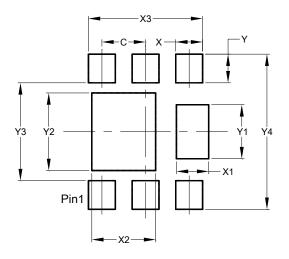
U-DFN2020-6										
	(Type F)									
Dim	Min	Max	Тур							
Α	0.57	0.63	0.60							
A1	0.00	0.05	0.03							
A3	0.15									
b	0.25	0.35	0.30							
D	1.95	2.05	2.00							
D2	0.85	1.05	0.95							
D2a	0.33	0.43	0.38							
E	1.95	2.05	2.00							
E2	1.05	1.25	1.15							
E2a	0.65	0.75	0.70							
е		0.65 BS	С							
e2	C	).863 BS	SC							
e3	Ţ	0.70 BS	С							
e4	C	).325 BS	SC							
k		0.37 BS	С							
k1	0.15 BSC									
k2	0.36 BSC									
L	0.225 0.325 0.275									
z	0.20 BSC									
z1	0.110 BSC									
z2		0.20 BS	С							
Ali C	imens	ions in	mm							

## Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

### U-DFN2020-6 (Type F)

U-DFN2020-6 (Type F)



Dimensions	Value
	(in mm)
С	0.650
Х	0.400
X1	0.480
X2	0.950
X3	1.700
Y	0.425
Y1	0.800
Y2	1.150
Y3	1.450
Y4	2.300

# ww.ulodes.com/package-outlines.h



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